

# Si53102-A1/A2/A3 Data Sheet

## PCI-Express Gen 1, Gen 2, Gen 3, and Gen 4 1:2 Fan-out Clock Buffer

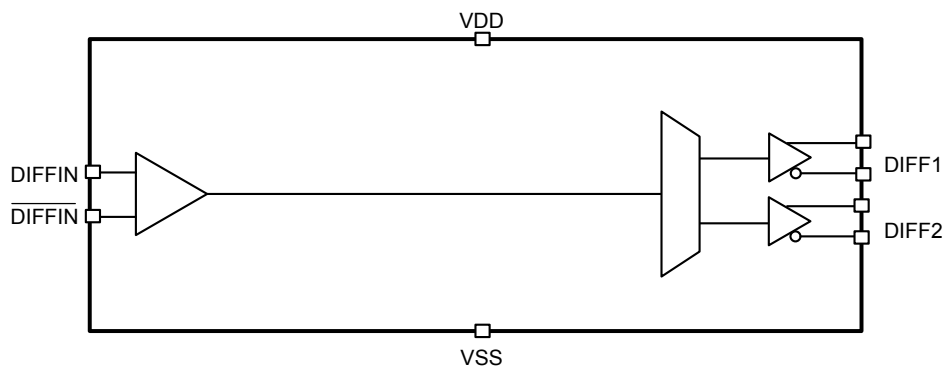
Si53102-A1/A2/A3 is a family of high-performance 1:2 PCIe fan output buffers. This low-additive-jitter clock buffer family is compliant to PCIe Gen 1, Gen 2, Gen 3, and Gen 4 specifications. The ultra-small footprint (1.4x1.6 mm) and industry-leading low power consumption make the Si53102-A1/A2/A3 the ideal clock solution for consumer and embedded applications. Measuring PCIe clock jitter is quick and easy with the Skyworks PCIe Clock Jitter Tool. Download it for free at <https://www.skyworksinc.com/en/application-pages/pci-express-learning-center>.

### Applications

- Network Attached Storage
- Multi-function Printer
- Wireless Access Point
- Server/Storage

### KEY FEATURES

- PCI-Express Gen 1, Gen 2, Gen 3, and Gen 4 common clock compliant
- Two low-power PCIe clock outputs
- Supports Serial-ATA (SATA) at 100 MHz
- No termination resistors required for differential clocks
- 2.5 V or 3.3 V Power supply
- Spread Spectrum Tolerant
- Extended Temperature Range
  - -40 to 85 °C
- Small package 8-pin TDFN (1.4 x 1.6 mm)
- For PCIe Gen 1: Si53102-A1
- For PCIe Gen 2: Si53102-A2
- For PCIe Gen 3/4: Si53102-A3



## 1. Ordering Guide

**Table 1.1. Ordering Guide**

Part Number	Package Type	Temperature
Si53102-A1-GM	8-pin TDFN	Extended, –40 to 85 °C
Si53102-A1-GMR	8-pin TDFN—Tape and Reel	Extended, –40 to 85 °C
Si53102-A2-GM	8-pin TDFN	Extended, –40 to 85 °C
Si53102-A2-GMR	8-pin TDFN—Tape and Reel	Extended, –40 to 85 °C
Si53102-A3-GM	8-pin TDFN	Extended, –40 to 85 °C
Si53102-A3-GMR	8-pin TDFN—Tape and Reel	Extended, –40 to 85 °C

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## 2. Electrical Specifications

**Table 2.1. Recommended Operating Conditions**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply Voltage (3.3 V Supply)	$V_{DD}$	3.3 V $\pm$ 10%	2.97	3.3	3.63	V
Supply Voltage (2.5 V Supply)	$V_{DD}$	2.5 V $\pm$ 10%	2.25	2.5	2.75	V

**Table 2.2. DC Electrical Specifications**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Operating Voltage ( $V_{DD}$ = 3.3 V)	$V_{DD}$	3.3 V $\pm$ 10%	2.97	3.30	3.63	V
Operating Voltage ( $V_{DD}$ = 2.5 V)	$V_{DD}$	2.5 V $\pm$ 10%	2.25	2.5	2.75	V
Operating Supply Current	$I_{DD}$	Full Active	—	—	15	mA
Input Pin Capacitance	$C_{IN}$	Input Pin Capacitance	—	3	5	pF
Output Pin Capacitance	$C_{OUT}$	Output Pin Capacitance	—	—	5	pF

**Table 2.3. AC Electrical Specifications<sup>1, 2, 3</sup>**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>DIFFIN at 0.7 V</b>						
Input frequency	$F_{in}$		10	100	175	MHz
DIFFIN and DIFFINb Rising/Falling Slew Rate	$T_R / T_F$	Single ended measurement: $V_{OL} = 0.175$ to $V_{OH} = 0.525$ V (Averaged)	0.6	—	4	V/ns
Differential Input High Voltage	$V_{IH}$		150	—	—	mV
Differential Input Low Voltage	$V_{IL}$		—	—	-150	mV
Crossing Point Voltage at 0.7 V Swing	$V_{OX}$	Single-ended measurement	250	—	550	mV
Vcross Variation Over All edges	$\Delta V_{OX}$	Single-ended measurement	—	—	140	mV
Differential Ringback Voltage	$V_{RB}$		-100	—	100	mV
Time before Ringback Allowed	$T_{STABLE}$		500	—	—	ps
Absolute Maximum Input Voltage	$V_{MAX}$			—	1.15	V
Absolute Minimum Input Voltage	$V_{MIN}$		-0.3	—	—	V

Parameter	Symbol	Condition	Min	Typ	Max	Unit
DIFFIN and DIFFINb Duty Cycle	$T_{DC}$	Measured at crossing point VOX	45	—	55	%
Rise/Fall Matching	$T_{RFM}$	Determined as a fraction of $2 \times (TR - TF)/(TR + TF)$	—	—	20	%
<b>DIFF Clocks</b>						
Duty Cycle	$T_{DC}$	Measured at crossing point VOX	45	—	55	%
Output Skew	$T_{SKEW}$	Measured at 0 V differential	—	—	100	ps
Frequency Accuracy	$F_{ACC}$	All output clocks	—	—	100	ppm
Slew Rate	$t_{r/f2}$	Measured differentially from $\pm 150$ mV	0.6	—	4.0	V/ns
PCIe Gen 1 Pk-Pk Additive Jitter	$Pk-Pk_{GEN1}$	PCIe Gen 1 Si53102-A1	—	—	10	ps
PCIe Gen 2 Additive Phase Jitter	$RMS_{GEN2}$	10 kHz < F < 1.5 MHz, Si53102-A2	—	—	0.50	ps
PCIe Gen 2 Additive Phase Jitter	$RMS_{GEN2}$	1.5 MHz < F < Nyquist, Si53102-A2	—	—	0.50	ps
PCIe Gen 3 Additive Phase Jitter	$RMS_{GEN3}$	Includes PLL BW 2–4 MHz, CDR = 10 MHz, Si53102-A3, VDD=3.3 V	—	—	0.22	ps
		Includes PLL BW 2–4 MHz, CDR = 10 MHz, Si53102-A3, VDD=2.5V	—	—	0.25	ps
PCIe Gen 4 Additive Phase Jitter	$RMS_{GEN4}$	PCIe Gen4, VDD=3.3V	—	—	0.22	ps
		PCIe Gen4, VDD=2.5V			0.25	ps
Crossing Point Voltage at 0.7 V Swing	$V_{OX}$	VDD = 3.3 V	300	—	550	mV
		VDD = 2.5 V	200	—	550	mV
<b>Enable/Disable and Setup</b>						
Clock Stabilization from Powerup	$T_{STABLE}$	Power up to first output	—	—	3.0	ms
<b>Note:</b>						
1. Visit <a href="http://www.pcisig.com">www.pcisig.com</a> for complete PCIe specifications						
2. Gen 4 specifications based on the PCI-Express Base Specification 4.0 rev. 0.5.						
3. Download the Skyworks PCIe Clock Jitter Tool at <a href="https://www.skyworksinc.com/en/application-pages/pci-express-learning-center">https://www.skyworksinc.com/en/application-pages/pci-express-learning-center</a> .						

**Table 2.4. Thermal Conditions**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Temperature, Storage	$T_S$	Non-functional	-65		150	°C
Temperature, Operating Ambient	$T_A$	Functional	-40		85	°C
Temperature, Junction	$T_J$	Functional	—		150	°C
Dissipation, Junction to Case	$\theta_{JC}$	JEDEC (JESD 51)	—		38.3	°C/W
Dissipation, Junction to Ambient	$\theta_{JA}$	JEDEC (JESD 51)	—		90.4	°C/W

**Table 2.5. Absolute Maximum Conditions**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Main Supply Voltage	$V_{DD\_3.3V}$		—		4.6	V
Input Voltage	$V_{IN}$	Relative to $V_{SS}$	-0.5		4.6	$V_{DC}$
ESD Protection (Human Body Model)	$ESD_{HBM}$	JEDEC (JESD 22-A114)	2000		—	V
Flammability Rating	UL-94	UL (Class)	V-0			

### 3. Test and Measurement Setup

The following figures show the test load configurations for the differential clock signals.

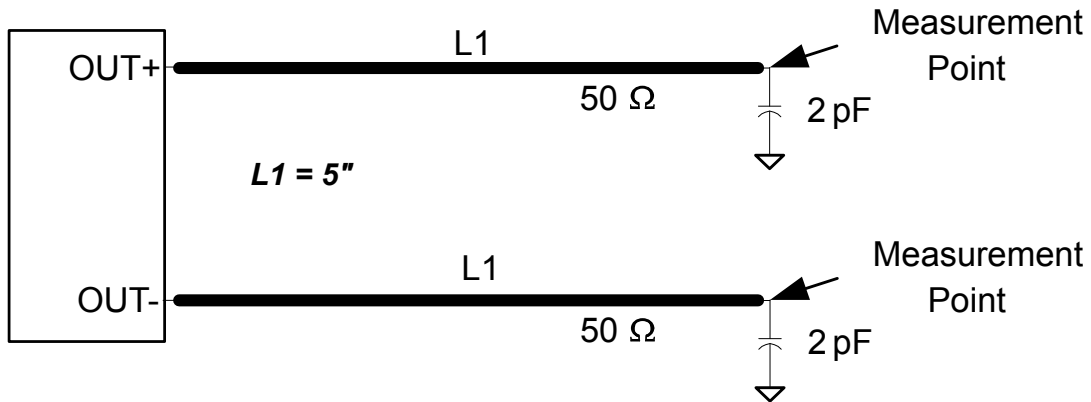


Figure 3.1. 0.7 V Differential Load Configuration

The outputs from this device can also support LVDS, LVPECL, or CML differential signaling levels using alternative termination. For recommendations on how to achieve this, see [“AN781: Alternative Output Termination for Si5211x, Si5213x, Si5214x, Si5216x, Si5310x, Si5311x, and Si5315x PCIe Clock Generator and Buffer Families.”](#)

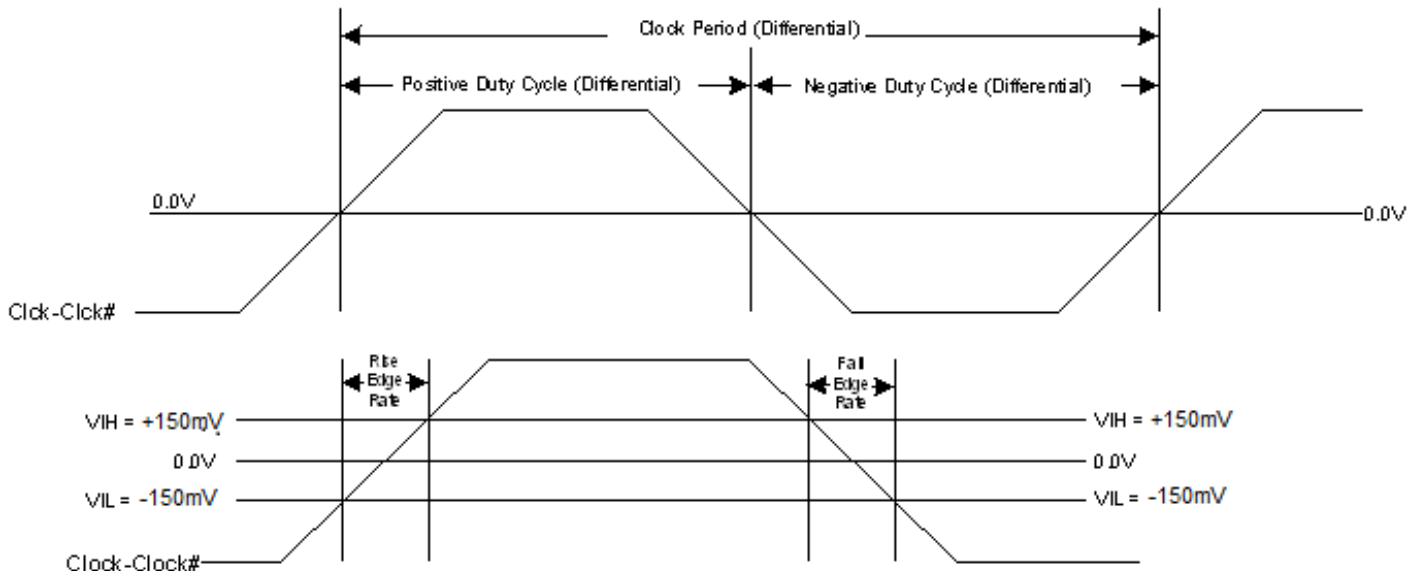


Figure 3.2. Differential Measurement for Differential Output Signals (AC Parameters Measurement)

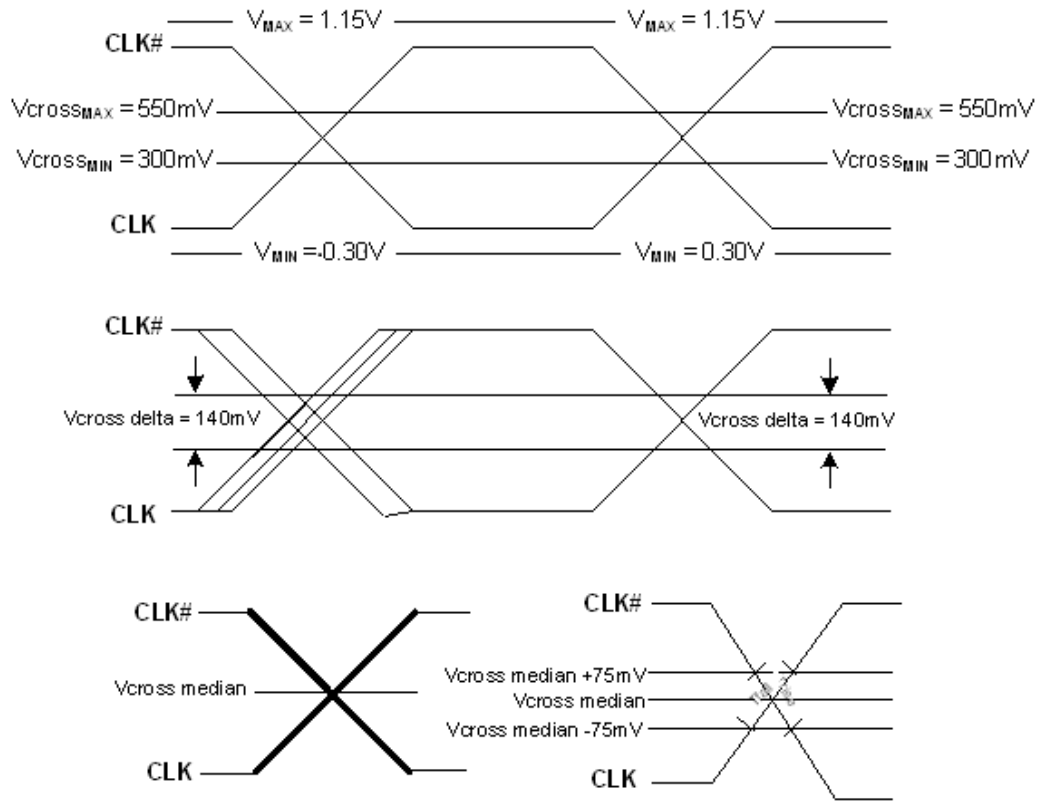


Figure 3.3. Single-Ended Measurement for Differential Output Signals (AC Parameters Measurement)



#### 4. Recommended Design Guideline

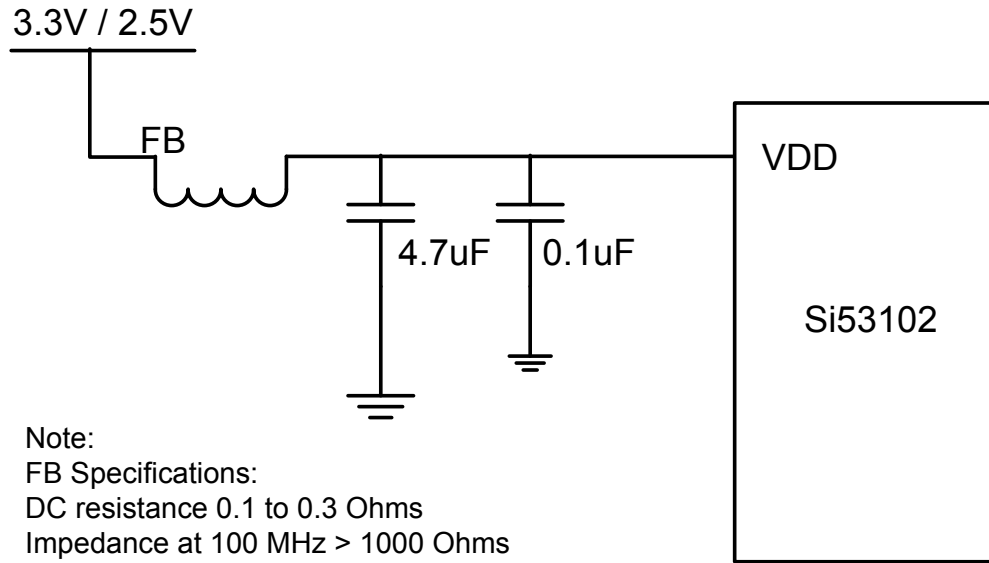


Figure 4.1. Recommended Application Schematic

## 5. Pin Descriptions

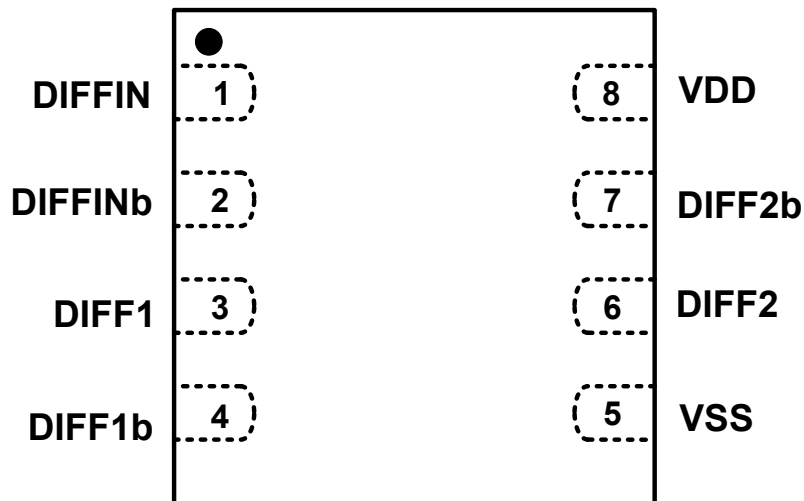


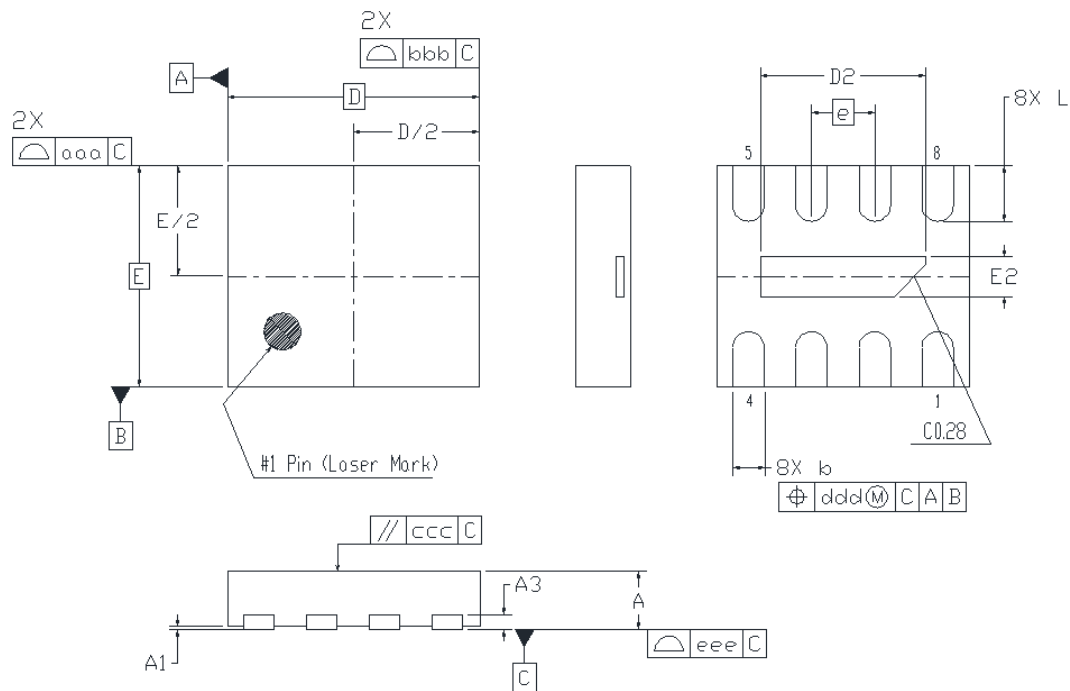
Figure 5.1. 8-Pin TDFN

Table 5.1. Si53102-Ax-GM 8-Pin TDFN Descriptions

Pin #	Name	Type	Description
1	DIFFIN	O, DIF	0.7 V, 100 MHz differentials clock input
2	DIFFINb	O, DIF	0.7 V, 100 MHz differentials clock input
3	DIFF1	O, DIF	0.7 V, 100 MHz differential clock output
4	DIFF1b	O, DIF	0.7 V, 100 MHz differential clock output
5	GND	GND	Ground
6	DIFF2	O, DIF	0.7 V, 100 MHz differential clock output
7	DIFF2b	O, DIF	0.7 V, 100 MHz differential clock output
8	VDD	PWR	2.5 V or 3.3 V Power supply

## 6. Package Outline

The figure below illustrates the package details for the Si53102-A1-A2-A3 in an 8-Pin TDFN package. The table lists the values for the dimensions shown in the illustration.



**Figure 6.1. 8-Pin TDFN Package Drawing**

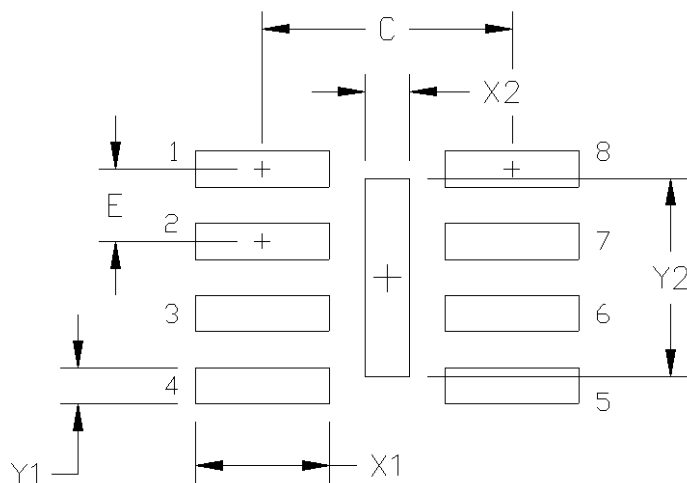
**Table 6.1. Package Diagram Dimensions**

Dimension	Min	Nom	Max
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3	0.20 REF.		
b	0.15	0.20	0.25
D	1.60 BSC		
D2	1.00	1.05	1.10
e	0.40 BSC		
E	1.40 BSC		
E2	0.20	0.25	0.30
L	0.30	0.35	0.40
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.07		
eee	0.08		

Dimension	Min	Nom	Max
<b>Note:</b> 1. All dimensions shown are in millimeters (mm) unless otherwise noted. 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994. 3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.			

## 7. Land Pattern

The following figure illustrates the land pattern details for the Si53102-A1-A2-A3 in an 8-Pin TDFN package. The table lists the values for the dimensions shown in the illustration.



**Figure 7.1. 8-Pin TDFN Land Pattern**

**Table 7.1. Land Pattern Dimensions**

Dimension	mm
C1	1.40
E	0.40
X1	0.75
Y1	0.20
X2	0.25
Y2	1.10

### Notes:

#### General

1. All dimensions shown are in millimeters (mm).
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60  $\mu\text{m}$  minimum, all the way around the pad.

#### Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 1:1 for all pads.

#### Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

## 8. Revision History

### 8.1 Revision 1.0

July 25, 2013

Full-production revision from Rev 0.4

- Updated AC Electrical Specifications table.
  - Updated input frequency min and max specs.
- Updated Test and Measurement Setup section.
  - Added text and reference to AN781.

### 8.2 Revision 1.1

August 5, 2013

- Moved Recommended Design Guideline section.
- Updated Pin Descriptions.
- Updated Package Outline.
- Added Land Pattern.

### 8.3 Revision 1.2

December 2, 2015

- Updated Features.
- Updated Description.
- Updated AC Electrical Specifications table.

### 8.4 Revision 1.3

July 21, 2017

- Updated IDD max specification.
- Separated VOX into 2.5 V and 3.3 V specifications.
- Separated PCIe Gen3 jitter into 2.5 V and 3.3 V specifications.
- Separated PCIe Gen4 jitter into 2.5 V and 3.3 V specifications.

### 8.5 Revision 1.4

July 28, 2017

- Updated [2. Electrical Specifications](#).
  - Updated PCIe Gen 4 Additive Phase Jitter max spec.
- Updated [6. Package Outline](#).
  - Added notes to [Table 6.1 Package Diagram Dimensions on page 11](#).